ZXTN2040F

40V NPN MEDIUM POWER PLANAR TRANSISTOR IN SOT23

Features

- BV_{CEO} > 40V
- I_C = 1A Continuous Collector Current
- Low Saturation Voltage $V_{CE(sat)}$ < 500mV @ 1A
- Complementary Part Number ZXTP2041F
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT23
- Case material: Molded Plastic. "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.008 grams (Approximate)

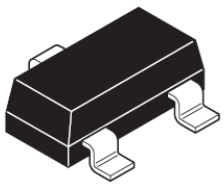
Description

This transistor combines high gain, high current operation and low saturation voltage making it ideal for power MOSFET gate driving and low loss power switching.

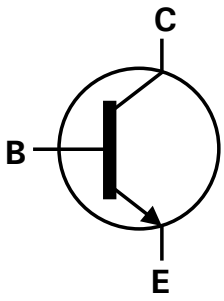
Applications

- Power MOSFET date driving
- Low loss power switching

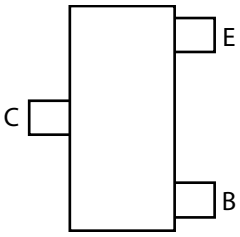
SOT23



Top View



Device Symbol



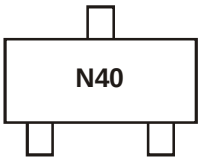
Top View
Pin Configuration

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN2040FTA	N40	7	8	3,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



N40 = Product Type Marking Code

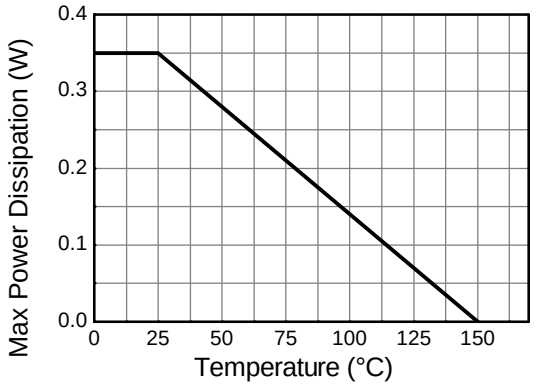
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6	V
Continuous Collector Current (Note 5)	I_C	1	A
Peak Pulse Current	I_{CM}	2	A
Peak Base Current	I_{BM}	1	A

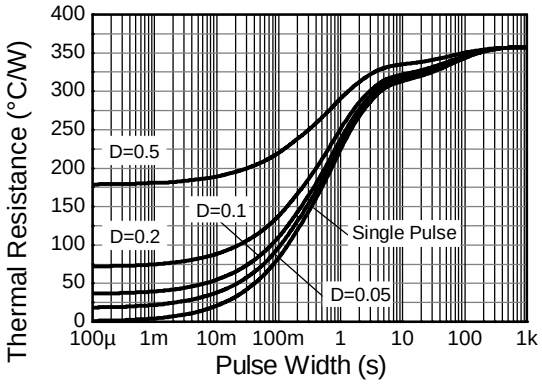
Thermal Characteristics

Characteristic		Symbol	Value	Unit
Collector Power Dissipation	(Note 5)	P_D	310	mW
	(Note 6)		350	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	403	°C/W
	(Note 6)		357	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	350	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

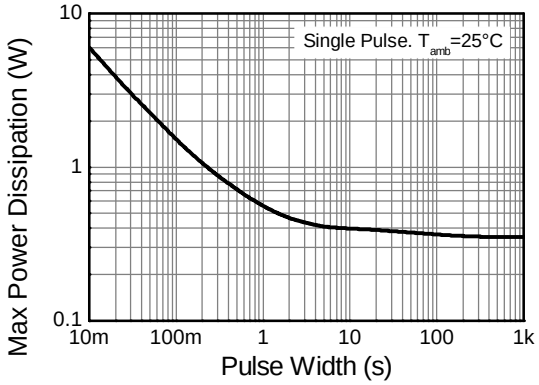
Notes: 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition.
6. Same as Note 5, expect the device is mounted on 15mm X 15mm X 1.6mm FR4 PCB.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).



Derating Curve



Transient Thermal Impedance



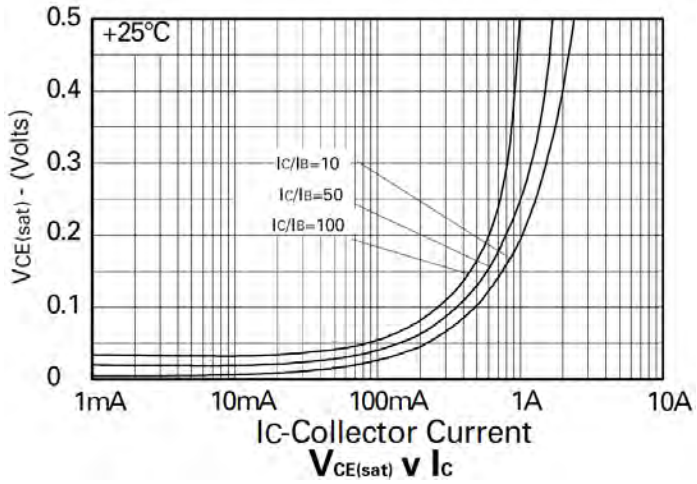
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

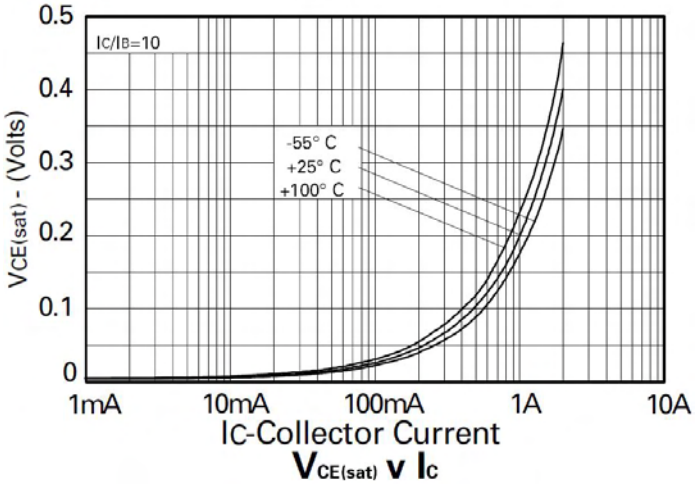
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	40	—	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (base open) (Note 8)	BV_{CEO}	40	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	6	—	—	V	I_E = 100µA
Collector-emitter cut-off current	I_{CES}	—	—	100	nA	V_{CE} = 30V
Collector-base Cut-off Current	I_{CBO}	—	—	100	nA	V_{CB} = 30V
Emitter-base Cut-off Current	I_{EBO}	—	—	100	nA	V_{EB} = 5V
ON CHARACTERISTICS (Note 8)						
Static Forward Current Transfer Ratio	h_{FE}	300 300 200 35	—	— 900 — —	—	I_C = 1mA, V_{CE} = 5V I_C = 500mA, V_{CE} = 5V I_C = 1A, V_{CE} = 5V I_C = 2A, V_{CE} = 5V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	200 300 500	mV	I_C = 100mA, I_B = 1mA I_C = 500mA, I_B = 50mA I_C = 1A, I_B = 100mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	—	1.1	V	I_C = 1A, I_B = 100mA
Base-Emitter On Voltage	$V_{BE(on)}$	—	—	1.0	V	I_C = 1A, V_{CE} = 5V
SMALL SIGNAL CHARACTERISTICS (Note 8)						
Transition Frequency	f_T	150	—	—	MHz	I_C = 50mA, V_{CE} = 10V, f = 100MHz
Output Capacitance	C_{obo}	—	—	10	pF	V_{CB} = 10V, f = 1MHz

Notes: 8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%

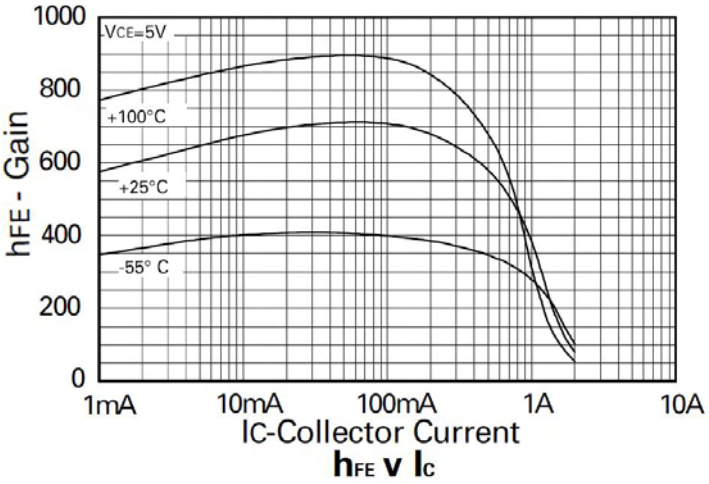
Typical Electrical Characteristics



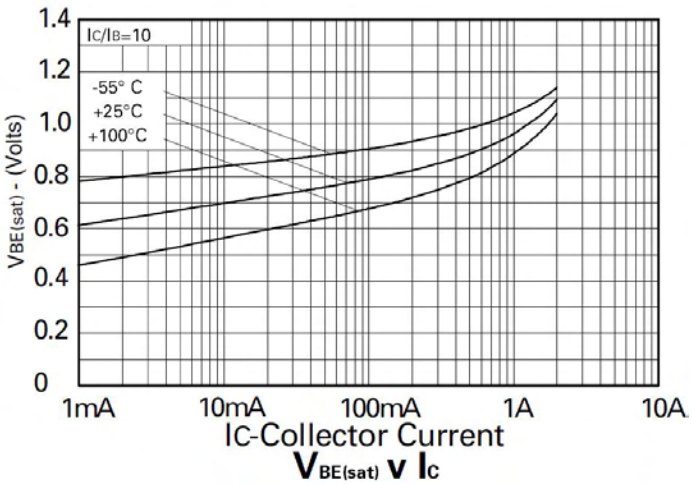
$V_{CE(sat)}$ v I_C



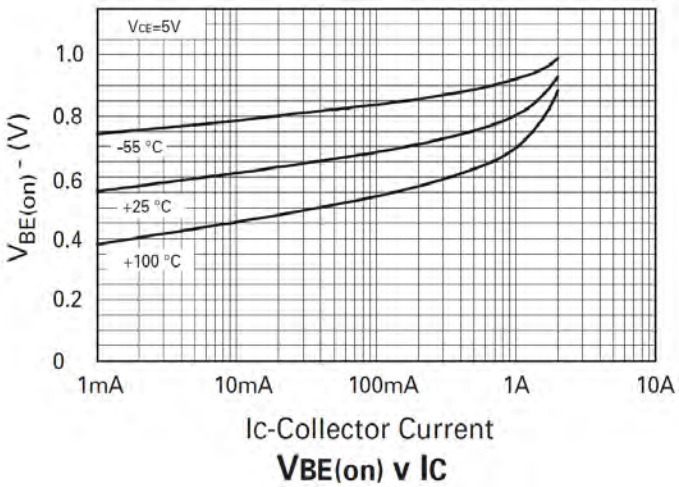
$V_{CE(sat)}$ v I_C



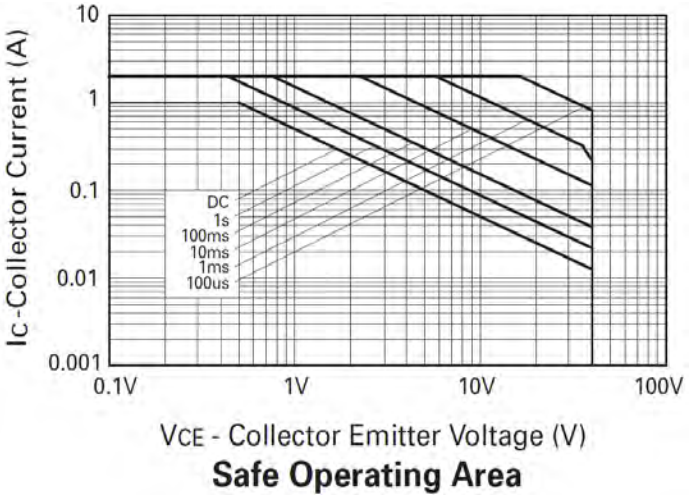
h_{FE} v I_C



$V_{BE(sat)}$ v I_C



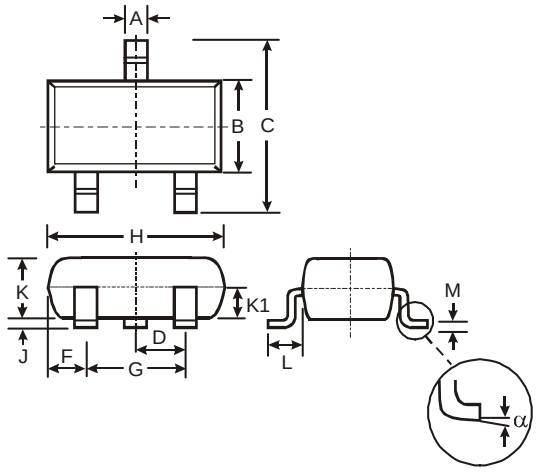
$V_{BE(on)}$ v I_C



Safe Operating Area

Package Outline Dimensions

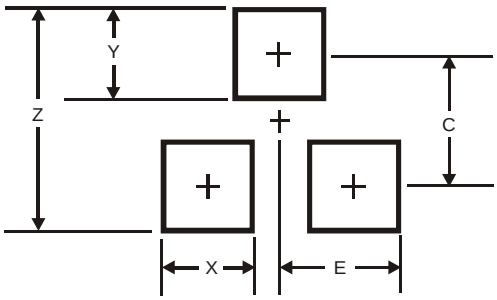
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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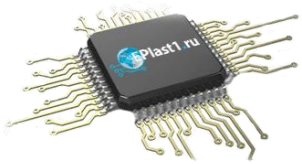

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